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FAIRCHILD

SEMICONDUCTOR

74ALVCR162601

Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs and 26 Ω Series Resistors in the Outputs

General Description

The 74ALVCR162601, 18-bit universal bus transceiver, combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock can be controlled by the clock-enable (CLKENAB and CLKENBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH-to-LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. Output-enable OEAB is active-LOW. When OEAB is HIGH, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses OEBA, LEBA, CLKBA and CLKENBA.

The 74ALVCR162601 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V. The 74ALVCR162601 is also designed with 26Ω series resistors on both the A and B Port outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

Features

- 1.65–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- \blacksquare 26 Ω series resistors on both the A and B Port outputs.
- t_{PD} (A to B, B to A)
 - 4.3 ns max for 3.0V to 3.6V V_{CC}
 - 5.1 ns max for 2.3V to 2.7V V_{CC}
 - 9.2 ns max for 1.65V to 1.95V V_{CC}
- Power-down HIGH impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Uses patented noise/EMI reduction circuitry
- Latchup conforms to JEDEC JED78
- ESD performance:

Human body model > 2000V Machine model >200V

Note 1: To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
4ALVCR162601T	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Devices also available in Ta	pe and Reel. Specify	by appending the suffix letter "X" to the ordering code.

74ALVCR162601

Connection Diagram

	lagrain		
			I
OEAB -	1	56	CLKENAB
LEAB —	2	55	- CLKAB
A ₁ —	3	54	— B ₁
GND —	4	53	- GND
A ₂ —	5	52	— В ₂
A3 —	6	51	— B ₃
v _{cc} —	7	50	-v _{cc}
A4 —	8	49	— В ₄
A ₅ —	9	48	— B ₅
A ₆ —	10	47	— ^в 6
GND —	11	46	- GND
A ₇ —	12	45	— В ₇
A ₈ —	13	44	— B ₈
A ₉ —	14	43	— В ₉
A ₁₀ —	15	42	— ^в 10
A ₁₁ -	16	41	— В ₁₁
A ₁₂ —	17	40	— ^в 1 2
GND —	18	39	— GND
A ₁₃ —	19	38	— В _{1 3}
A ₁₄ —	20	37	— ^В 1 4
A ₁₅ —	21	36	— B ₁₅
v _{cc} —	22	35	-v _{cc}
A ₁₆ —	23	34	— B ₁₆
A ₁₇ —	24	33	— ^в 17
GND —	25	32	- GND
A ₁₈ —	26	31	— ^B 18
ОЕВА —	27	30	- CLKBA
LEBA —	28	29	- CLKENBA
	L		I

Pin Descriptions

Pin Names	Description
OEAB, OEBA	Output Enable Inputs (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
CLKENAB, CLKENBA	Clock Enable Inputs
A ₁ -A ₁₈	Side A Inputs or 3-STATE Outputs
B ₁ -B ₁₈	Side B Inputs or 3-STATE Outputs

Function Table (Note 2)

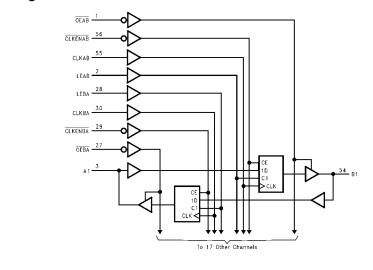
	Outputs				
CLKENAB	OEAB	LEAB	CLKAB	A _n	B _n
Х	Н	Х	х	Х	Z
Х	L	н	х	L	L
Х	L	н	х	Н	н
Н	L	L	х	Х	B ₀ (Note 3)
Н	L	L	х	Х	B ₀ (Note 3)
L	L	L	\uparrow	L	L
L	L	L	\uparrow	Н	н
L	L	L	L	Х	B ₀ (Note 3)
L	L	L	н	Х	B ₀ (Note 4)

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial (HIGH or LOW, inputs may not float) Z = HIGH Impedance Note 2: A-to-B data flow is shown; B-to-A flow is similar but uses $\overline{\text{OEBA}},$ LEBA, CLKBA, and $\overline{\text{CLKENBA}}.$

Note 3: Output level before the indicated steady-state input conditions were established

Note 4: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

Logic Diagram



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Absolute Maximum Ratings(Note 5)

Supply Voltage (V _{CC})	-0.5V to +4.6V
DC Input Voltage (V _I)	-0.5V to 4.6V
Output Voltage (V _O) (Note 6)	–0.5V to V _{CC} +0.5V
DC Input Diode Current (IIK)	
V ₁ < 0V	–50 mA
DC Output Diode Current (I _{OK})	
V _O < 0V	–50 mA
DC Output Source/Sink Current	
(I _{OH} /I _{OL})	±50 mA
DC V _{CC} or GND Current per	
Supply Pin (I _{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	$-65^{\circ}C$ to $+150^{\circ}C$

Recommended Operatin Conditions (Note 7)	g	i
Power Supply		9
Operating	1.65V to 3.6V	1
Input Voltage	0V to V _{CC}	Î
Output Voltage (V _O)	0V to V _{CC}	2
Free Air Operating Temperature (T_A)	$-40^{\circ}C$ to $+85^{\circ}C$	
Minimum Input Edge Rate ($\Delta t/\Delta V$)		
$V_{\rm IN} = 0.8V$ to 2.0V, $V_{\rm CC} = 3.0V$	10 ns/V	
Note 5: The Absolute Maximum Ratings are those	e values beyond which	

Note 5: The Absolute Maximum Hatings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

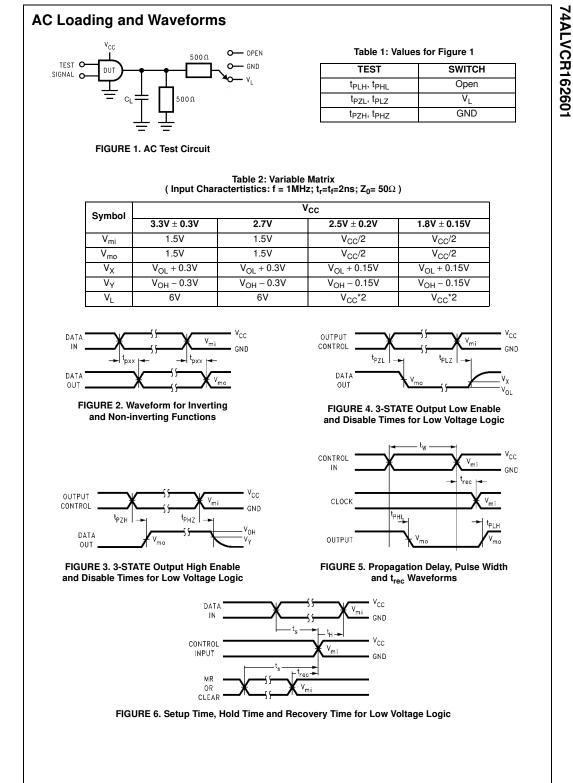
Note 7: Floating or unused control inputs must be held HIGH or LOW.

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		1.65 - 1.95	$0.65 \times V_{CC}$		
			2.3 - 2.7	1.7		V
			2.7 - 3.6	2.0		
V _{IL}	LOW Level Input Voltage		1.65 - 1.95		$0.35 \times V_{CC}$	
			2.3 - 2.7		0.7	V
			2.7 - 3.6		0.8	
/ _{ОН}	HIGH Level Output Voltage	I _{OH} = -100 μA	1.65 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -2 \text{ mA}$	1.65	1.2		
		$I_{OH} = -4 \text{ mA}$	2.3	1.9		
		$I_{OH} = -6 \text{ mA}$	2.3	1.7		V
			3.0	2.4		
		I _{OH} = -8 mA	2.7	2		
		$I_{OH} = -12 \text{ mA}$	3.0	2		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	1.65 - 3.6		0.2	
		I _{OL} = 2 mA	1.65		0.45	
		I _{OL} = 4 mA	2.3		0.4	
		I _{OL} = 6 mA	2.3		0.55	V
			3.0		0.55	
		I _{OL} = 8 mA	2.7		0.6	
		I _{OL} = 12 mA	3.0		0.8	
ОН	High Level Output Current		1.65		-2	
			2.3		-6	mA
			2.7		-8	IIIA
			3.0		-12	
OL	Low Level Output Current		1.65		2	
			2.3		6	mA
			2.7		8	IIIA
			3.0		12	
1	Input Leakage Current	$0 \le V_1 \le 3.6V$	1.65 - 3.6		±5.0	μA
oz	3-STATE Output Leakage	$0 \le V_O \le 3.6V$, $V_I = V_{IH}$ or V_{IL}	1.65 - 3.6		±10	μA
OFF	Power Off Leakage Current	$0V \le (V_I, V_O) \le 3.6V$	0		10	mA
сс	Quiescent Supply Current	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	3.6		40	μA
∆l _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μA

DC Electrical Characteristics

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				T _A =	-40°C to +	-85°C, R _L =	500 Ω			
Symbol			C _L =	50 pF			C _L =	30 pF		
	Parameter	V _{CC} = 3.	$.3V \pm 0.3V$	V _{cc}	= 2.7V	$V_{CC} = 2.5 \pm 0.2 V$			$8V \pm 0.15V$	Units
		Min	Max	Min	Max	Min	Max	Min	Max	
f _{MAX}	Maximum Clock Frequency	250		200		200		125		MHz
t _{PHL} , t _{PLH}	Propagation Delay A to B or B to A	1.1	4.3	1.3	5.1	0.8	4.6	1.5	9.2	ns
t _{PHL} , t _{PLH}	Propagation Delay Clock to A or B	1.1	4.9	1.3	6.0	0.8	5.5	1.5	9.8	ns
t _{PHL} , t _{PLH}	Propagation Delay LEBA or LEAB to A or B	1.1	4.9	1.3	6.3	0.8	5.8	1.5	9.8	ns
t _{PZL} , t _{PZH}	Output Enable Time OEBA or OEAB to A or B	1.1	4.8	1.3	6.4	0.8	5.9	1.5	9.8	ns
t _{PLZ} , t _{PHZ}	Output Disable Time OEBA or OEAB to A or B	1.1	4.8	1.3	5.4	0.8	4.9	1.5	8.8	ns
t _S	Setup Time	1.5		1.5		1.5		2.5		ns
t _H	Hold Time	1.0		1.0		1.0		1.0		ns
tw	Pulse Width	1.5		1.5		1.5		4.0		ns
C _{IN} C _{OUT}	Input Capacitance Output Capacitance			$V_I = 0V \text{ or }$ $V_I = 0V \text{ or }$				3.3 3.3	6 7	pF pF
C _{OUT}	Output Capacitance			$V_I = 0V \text{ or }$				3.3		pF
C _{PD}	Power Dissipation Capacitance	Outputs	s Enabled	f = 10 MHz	, C _L = 0 pF	:	_	3.3 2.5	20 20	pF



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